MPS2222AG Datasheet

DiGi Electronics Part Number	MPS2222AG-DG
Manufacturer	onsemi
Manufacturer Product Number	MPS2222AG
Description	TRANS NPN 40V 0.6A TO92
Detailed Description	Bipolar (BJT) Transistor NPN 40 V 600 mA 300MHz 625 mW Through Hole TO-92 (TO-226)

https://www.DiGi-Electronics.com

Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
MPS2222AG	onsemi
Series:	Product Status:
-	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
NPN	600 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ Ib, Ic:
40 V	1V @ 50mA, 500mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
10nA (ICBO)	100 @ 150mA, 10V
Power - Max:	Frequency - Transition:
625 mW	300MHz
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Through Hole
Package / Case:	Supplier Device Package:
TO-226-3, TO-92-3 Long Body	TO-92 (TO-226)
Base Product Number:	
MPS222	

Environmental & Export classification

Moisture Sensitivity Level (MSL):	REACH Status:
1 (Unlimited)	REACH Unaffected
ECCN:	HTSUS:
EAR99	8541.21.0075

MPS2222, MPS2222A

MPS2222A is a Preferred Device

General Purpose Transistors

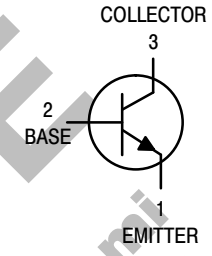
NPN Silicon

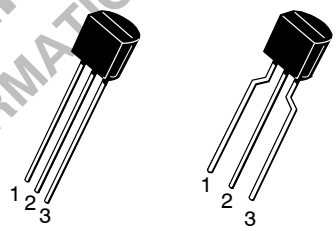
ON Semiconductor®

http://onsemi.com

Features

- Pb−Free Packages are Available*





TO−92
CASE 29
STYLE 1

STRAIGHT LEAD
BULK PACK

BENT LEAD
TAPE & REEL
AMMO PACK

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector−Emitter Voltage MPS2222 MPS2222A	V_{CEO}	 30 40	Vdc
Collector−Base Voltage MPS2222 MPS2222A	V_{CBO}	 60 75	Vdc
Emitter−Base Voltage MPS2222 MPS2222A	V_{EBO}	 5.0 6.0	Vdc
Collector Current − Continuous	I_C	600	mAdc
Total Device Dissipation @ T_A = 25°C Derate above 25°C	P_D	 625 5.0	 mW mW/°C
Total Device Dissipation @ T_C = 25°C Derate above 25°C	P_D	 1.5 12	 W mW/°C
Operating and Storage Junction Temperature Range	T_J, T_{stg}	−55 to +150	°C

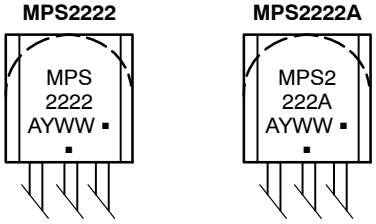
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction−to−Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction−to−Case	$R_{\theta JC}$	83.3	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MARKING DIAGRAMS



A = Assembly Location
Y = Year
WW = Work Week
▪ = Pb−Free Package
(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

MPS2222, MPS2222A

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage (I_C = 10 mAdc, I_B = 0)	MPS2222 MPS2222A	$V_{(BR)CEO}$	30 40	– –	Vdc
Collector – Base Breakdown Voltage (I_C = 10 μAdc, I_E = 0)	MPS2222 MPS2222A	$V_{(BR)CBO}$	60 75	– –	Vdc
Emitter – Base Breakdown Voltage (I_E = 10 μAdc, I_C = 0)	MPS2222 MPS2222A	$V_{(BR)EBO}$	5.0 6.0	– –	Vdc
Collector Cutoff Current (V_{CE} = 60 Vdc, $V_{EB(off)}$ = 3.0 Vdc)	MPS2222A	I_{CEX}	–	10	nAdc
Collector Cutoff Current		I_{CBO}			μAdc
(V_{CB} = 50 Vdc, I_E = 0)	MPS2222		–	0.01	
(V_{CB} = 60 Vdc, I_E = 0)	MPS2222A		–	0.01	
(V_{CB} = 50 Vdc, I_E = 0, T_A = 125°C)	MPS2222		–	10	
(V_{CB} = 50 Vdc, I_E = 0, T_A = 125°C)	MPS2222A		–	10	
Emitter Cutoff Current (V_{EB} = 3.0 Vdc, I_C = 0)	MPS2222A	I_{EBO}	–	100	nAdc
Base Cutoff Current (V_{CE} = 60 Vdc, $V_{EB(off)}$ = 3.0 Vdc)	MPS2222A	I_{BL}	–	20	nAdc
ON CHARACTERISTICS					
DC Current Gain		h_{FE}			–
(I_C = 0.1 mAdc, V_{CE} = 10 Vdc)			35	–	
(I_C = 1.0 mAdc, V_{CE} = 10 Vdc)			50	–	
(I_C = 10 mAdc, V_{CE} = 10 Vdc)			75	–	
(I_C = 10 mAdc, V_{CE} = 10 Vdc, T_A = −55°C)	MPS2222A only		35	–	
(I_C = 150 mAdc, V_{CE} = 10 Vdc) (Note 1)			100	300	
(I_C = 150 mAdc, V_{CE} = 1.0 Vdc) (Note 1)			50	–	
(I_C = 500 mAdc, V_{CE} = 10 Vdc) (Note 1)	MPS2222		30	–	
	MPS2222A		40	–	
Collector – Emitter Saturation Voltage (Note 1)		$V_{CE(sat)}$			Vdc
(I_C = 150 mAdc, I_B = 15 mAdc)	MPS2222		–	0.4	
	MPS2222A		–	0.3	
(I_C = 500 mAdc, I_B = 50 mAdc)	MPS2222		–	1.6	
	MPS2222A		–	1.0	
Base – Emitter Saturation Voltage (Note 1)		$V_{BE(sat)}$			Vdc
(I_C = 150 mAdc, I_B = 15 mAdc)	MPS2222		–	1.3	
	MPS2222A		0.6	1.2	
(I_C = 500 mAdc, I_B = 50 mAdc)	MPS2222		–	2.6	
	MPS2222A		–	2.0	
SMALL– SIGNAL CHARACTERISTICS					
Current – Gain – Bandwidth Product (Note 2)		f_T			MHz
(I_C = 20 mAdc, V_{CE} = 20 Vdc, f = 100 MHz)	MPS2222		250	–	
	MPS2222A		300	–	
Output Capacitance (V_{CB} = 10 Vdc, I_E = 0, f = 1.0 MHz)		C_{obo}	–	8.0	pF
Input Capacitance		C_{ibo}			pF
(V_{EB} = 0.5 Vdc, I_C = 0, f = 1.0 MHz)	MPS2222		–	30	
	MPS2222A		–	25	
Input Impedance		h_{ie}			kΩ
(I_C = 1.0 mAdc, V_{CE} = 10 Vdc, f = 1.0 kHz)	MPS2222A		2.0	8.0	
(I_C = 10 mAdc, V_{CE} = 10 Vdc, f = 1.0 kHz)	MPS2222A		0.25	1.25	
Voltage Feedback Ratio		h_{re}			X 10^{-4}
(I_C = 1.0 mAdc, V_{CE} = 10 Vdc, f = 1.0 kHz)	MPS2222A		–	8.0	
(I_C = 10 mAdc, V_{CE} = 10 Vdc, f = 1.0 kHz)	MPS2222A		–	4.0	
Small–Signal Current Gain		h_{fe}			–
(I_C = 1.0 mAdc, V_{CE} = 10 Vdc, f = 1.0 kHz)	MPS2222A		50	300	
(I_C = 10 mAdc, V_{CE} = 10 Vdc, f = 1.0 kHz)	MPS2222A		75	375	
Output Admittance		h_{oe}			μmhos
(I_C = 1.0 mAdc, V_{CE} = 10 Vdc, f = 1.0 kHz)	MPS2222A		5.0	35	
(I_C = 10 mAdc, V_{CE} = 10 Vdc, f = 1.0 kHz)	MPS2222A		25	200	
Collector Base Time Constant		$rb'C_c$			ps
(I_E = 20 mAdc, V_{CB} = 20 Vdc, f = 31.8 MHz)	MPS2222A		–	150	
Noise Figure		NF			dB
(I_C = 100 μAdc, V_{CE} = 10 Vdc, R_S = 1.0 kΩ, f = 1.0 kHz)	MPS2222A		–	4.0	

1. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.
2. f_T is defined as the frequency at which $|h_{fe}|$ extrapolates to unity.

MPS2222, MPS2222A

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Max	Unit
SWITCHING CHARACTERISTICS MPS2222A only					
Delay Time	(V_{CC} = 30 Vdc, $V_{BE(off)}$ = −0.5 Vdc, I_C = 150 mAdc, I_{B1} = 15 mAdc) (Figure 1)	t_d	–	10	ns
Rise Time		t_r	–	25	ns
Storage Time	(V_{CC} = 30 Vdc, I_C = 150 mAdc, I_{B1} = I_{B2} = 15 mAdc) (Figure 2)	t_s	–	225	ns
Fall Time		t_f	–	60	ns

SWITCHING TIME EQUIVALENT TEST CIRCUITS

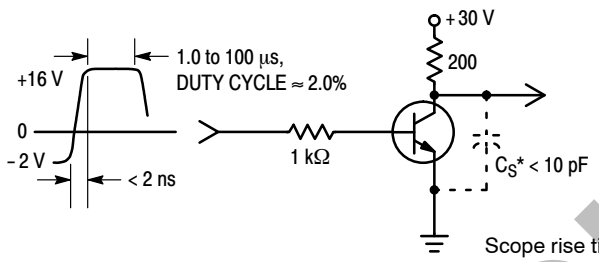


Figure 1. Turn−On Time

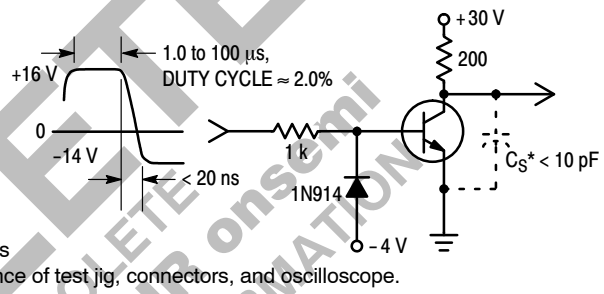


Figure 2. Turn−Off Time

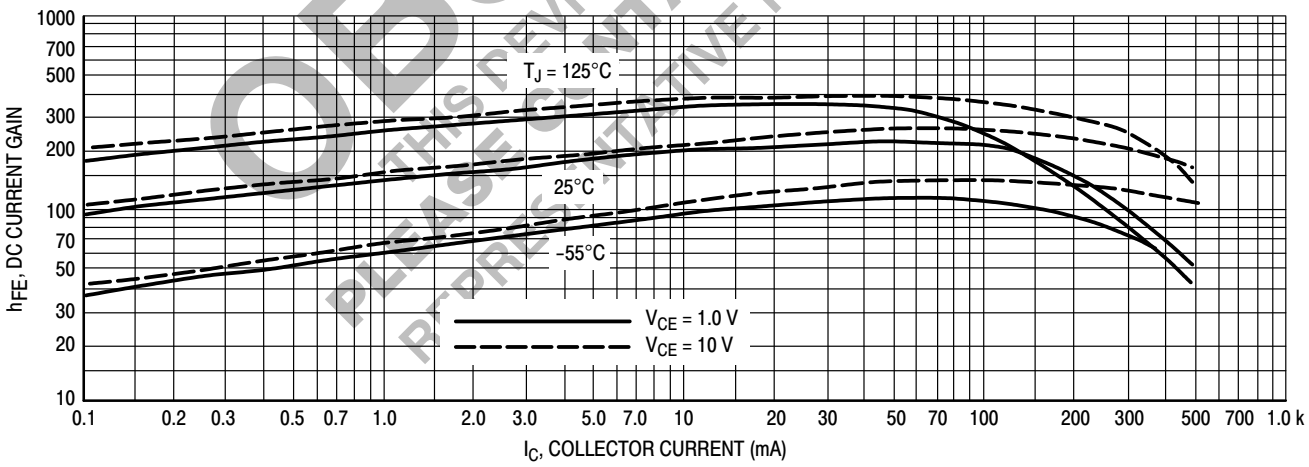


Figure 3. DC Current Gain

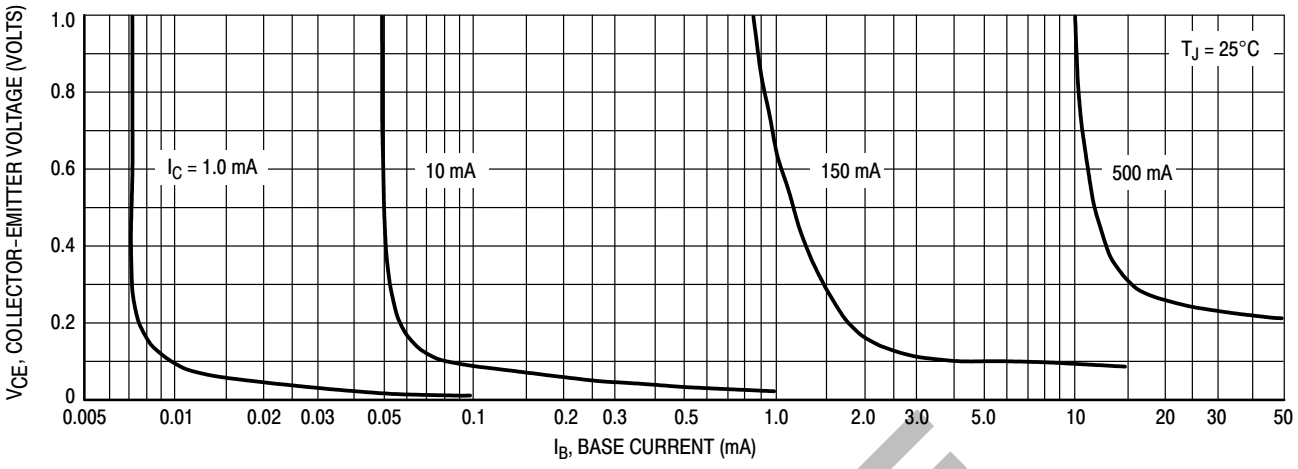


Figure 4. Collector Saturation Region

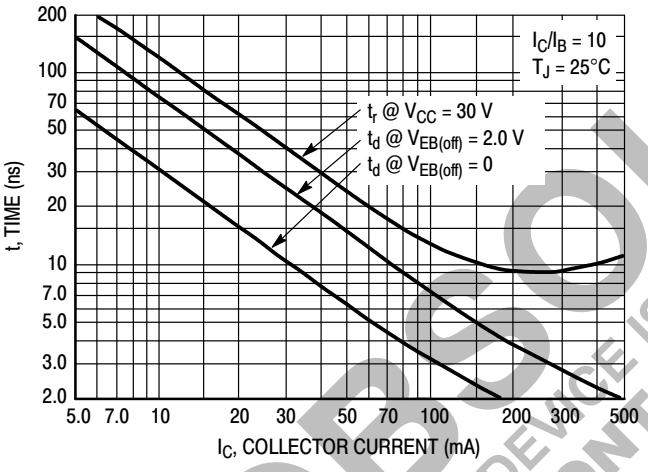


Figure 5. Turn – On Time

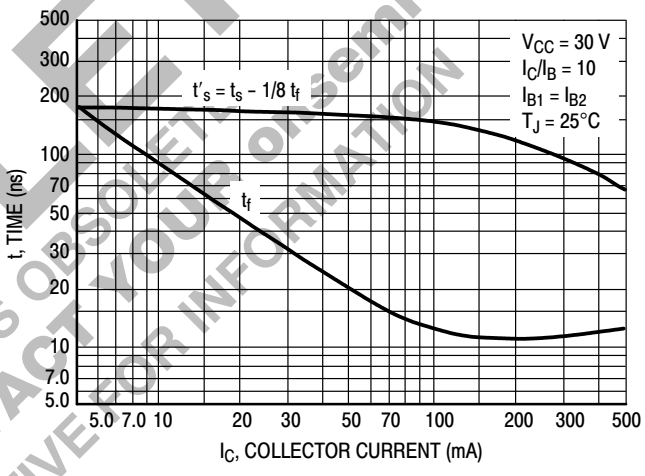


Figure 6. Turn – Off Time

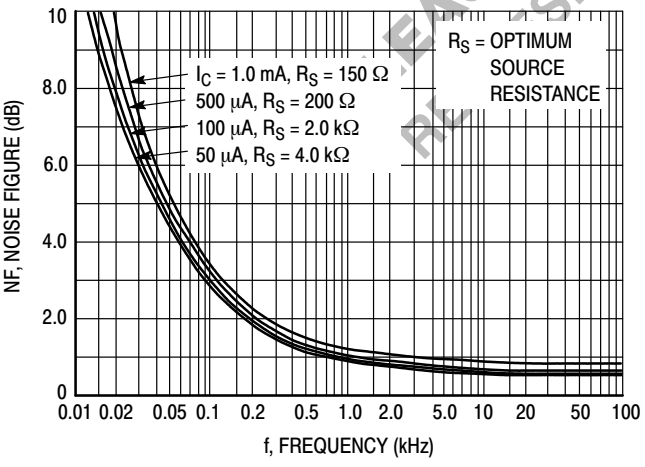


Figure 7. Frequency Effects

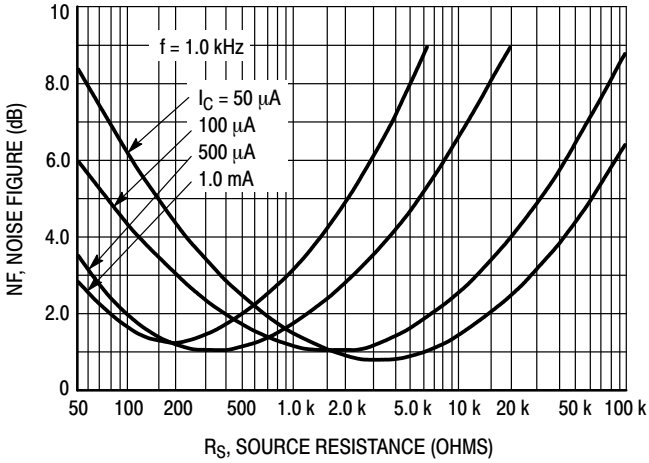


Figure 8. Source Resistance Effects

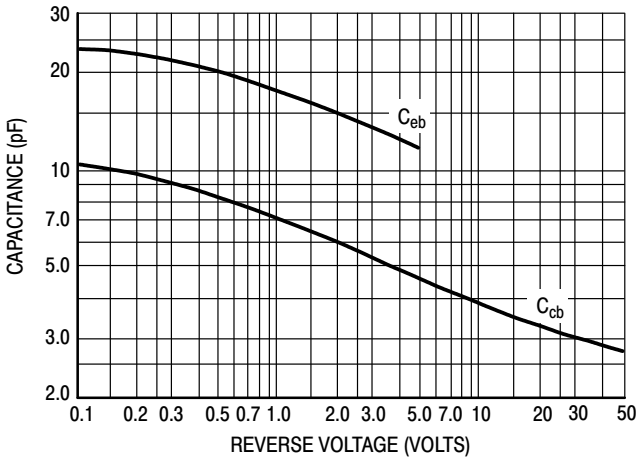


Figure 9. Capacitances

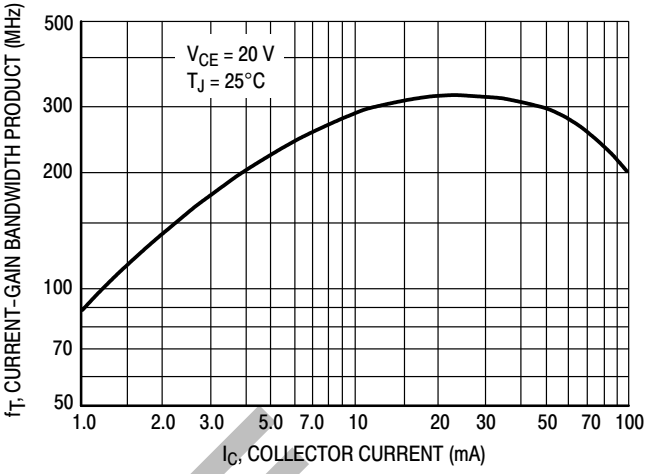


Figure 10. Current−Gain Bandwidth Product

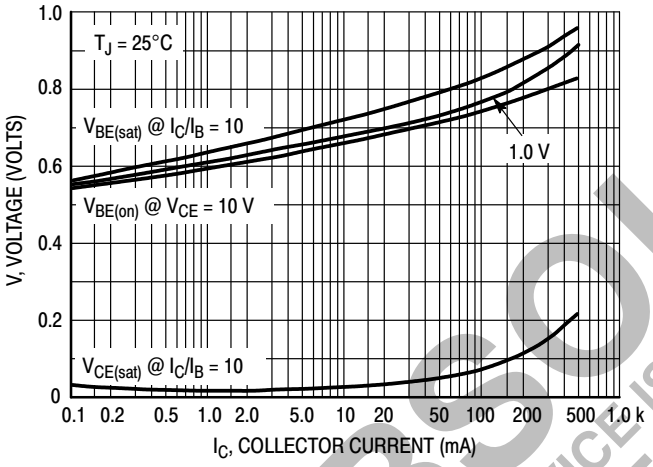


Figure 11. "On" Voltages

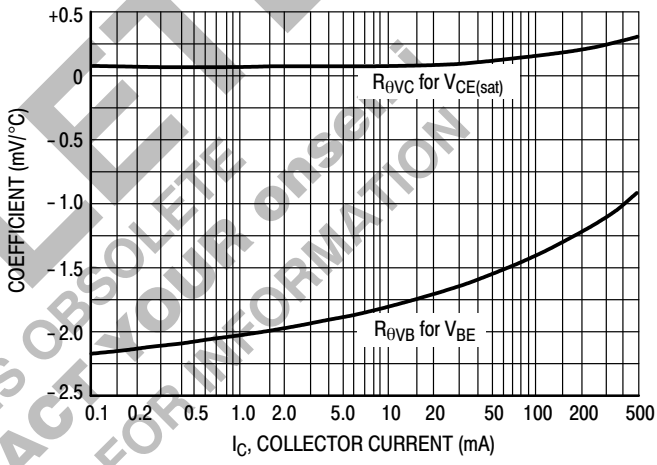


Figure 12. Temperature Coefficients

ORDERING INFORMATION

Device	Package	Shipping†
MPS2222G	TO−92 (Pb−Free)	5000 Units / Bulk
MPS2222RLRP	TO−92	2000 / Tape & Ammo Box
MPS2222RLRPG	TO−92 (Pb−Free)	2000 / Tape & Ammo Box
MPS2222A	TO−92	5000 Units / Bulk
MPS2222AG	TO−92 (Pb−Free)	5000 Units / Bulk
MPS2222ARLG	TO−92 (Pb−Free)	2000 / Tape & Reel
MPS2222ARLRA	TO−92	2000 / Tape & Reel
MPS2222ARLRAG	TO−92 (Pb−Free)	2000 / Tape & Reel

ORDERING INFORMATION

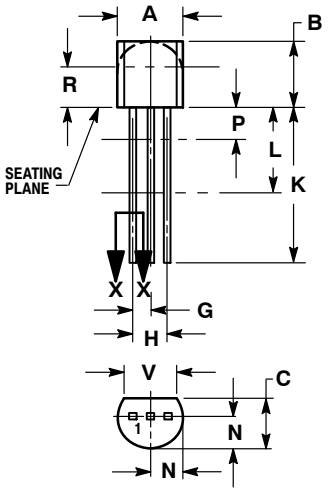
Device	Package	Shipping†
MPS2222ARLRMG	TO−92 (Pb−Free)	2000 / Tape & Reel
MPS2222ARLRPG	TO−92 (Pb−Free)	2000 / Tape & Ammo Box

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

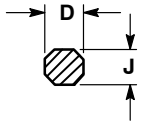
MPS2222, MPS2222A

PACKAGE DIMENSIONS

TO−92 (TO−226)
CASE 29−11
ISSUE AM



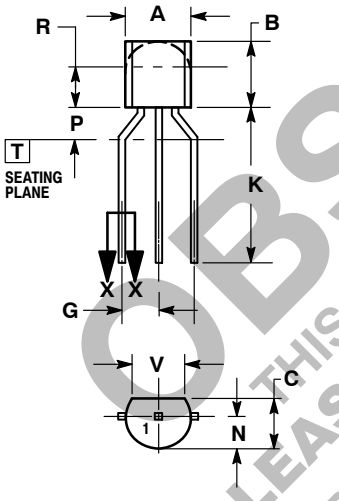
STRAIGHT LEAD
BULK PACK



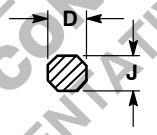
SECTION X−X

NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---



BENT LEAD
TAPE & REEL
AMMO PACK



SECTION X−X

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	MILLIMETERS	
DIM	MIN	MAX
A	4.45	5.20
B	4.32	5.33
C	3.18	4.19
D	0.40	0.54
G	2.40	2.80
J	0.39	0.50
K	12.70	---
N	2.04	2.66
P	1.50	4.00
R	2.93	---
V	3.43	---

STYLE 1:
PIN 1. EMITTER
2. BASE
3. COLLECTOR

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Literature Distribution Center for ON Semiconductor
P.O. Box 5163, Denver, Colorado 80217 USA
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ON Semiconductor Website: **www.onsemi.com**

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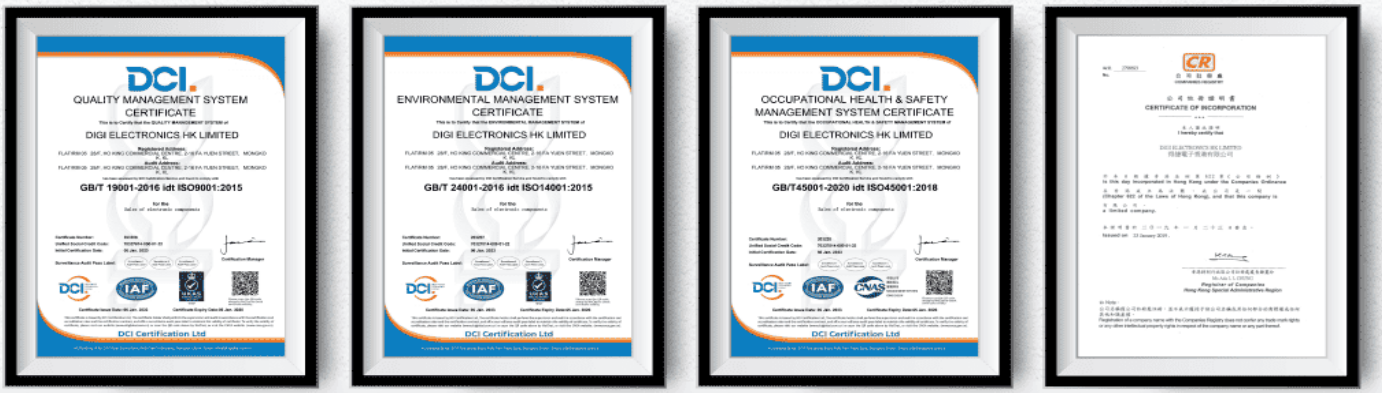

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